

PMEG2005EPK

20 V, 0.5 A low VF MEGA Schottky barrier rectifier Rev. 1 — 12 January 2012 Prod

Product data sheet

Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a leadless ultra small SOD1608 Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

1.2 Features and benefits

- Average forward current: I_{F(AV)} ≤ 0.5 A
- Reverse voltage: V_R ≤ 20 V
- Low forward voltage V_F ≤ 410 mV
- Low reverse current

- AEC-Q101 qualified
- Solderable side pads
- Package height typ. 0.37 mm
- Ultra small and leadless SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- LED backlight for mobile application
- Low power consumption applications
- Ultra high-speed switching
- Reverse polarity protection

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$I_{F(AV)}$	average forward current	square wave; δ = 0.5; f = 20 kHz; T _{amb} ≤ 130 °C	<u>[1]</u>	-	-	0.5	Α
		square wave; δ = 0.5; f = 20 kHz; T _{sp} ≤ 140 °C		-	-	0.5	Α
V_R	reverse voltage	T _j = 25 °C		-	-	20	V
V _F	forward voltage	I_F = 500 mA; pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$; T_j = 25 °C		-	360	410	mV
I _R	reverse current	V _R = 10 V; T _j = 25 °C		-	30	130	μΑ

^[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]		. 54 .
2	Α	anode	1 2	1 [] 2 sym001
			Transparent top view	
			SOD1608	

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMEG2005EPK	-	Leadless ultra small plastic package; 2 terminals	SOD1608

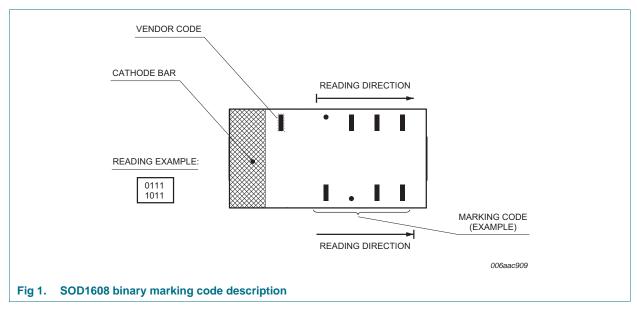
4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PMEG2005EPK	1000 0000

^[1] For SOD1608 binary marking code description, see Figure 1.

4.1 Binary marking code description



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Product data sheet

Rev. 1 — 12 January 2012

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_R	reverse voltage	T _j = 25 °C		-	20	V
I _F	forward current	T _{sp} ≤ 140 °C		-	0.5	Α
I _{F(AV)}	average forward current	square wave; δ = 0.5; f = 20 kHz; T _{amb} ≤ 130 °C	[1]	-	0.5	Α
		square wave; δ = 0.5; f = 20 kHz; T _{sp} ≤ 140 °C		-	0.5	Α
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \ \delta \le 0.5$		-	2	Α
I _{FSM}	non-repetitive peak forward current	square wave; $t_p = 8 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$		-	3	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2][3]	-	390	mW
			[4][3]	-	830	mW
			[1][3]	-	1470	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T_{stg}	storage temperature			-65	150	°C

^[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		[1][2][3]	-	-	320	K/W
			[1][4][3]	-	-	150	K/W
			-	-	85	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point		<u>[6]</u>	-	-	20	K/W

^[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

[6] Soldering point of cathode tab.

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^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Reflow soldering is the only recommended soldering method.

^[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Reflow soldering is the only recommended soldering method.

^[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[5] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

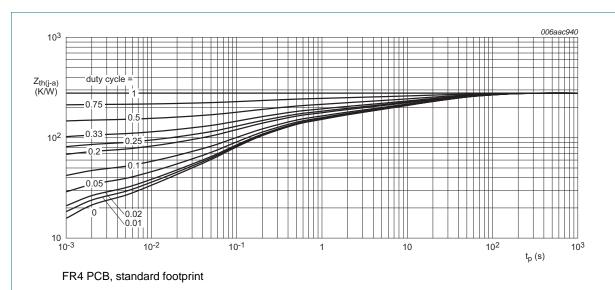


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

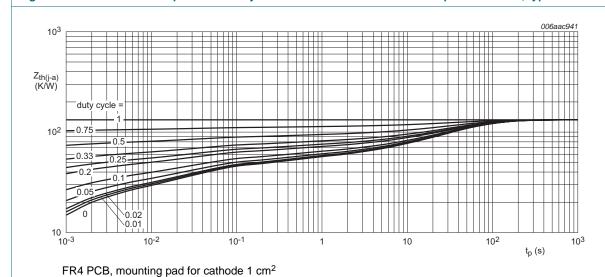
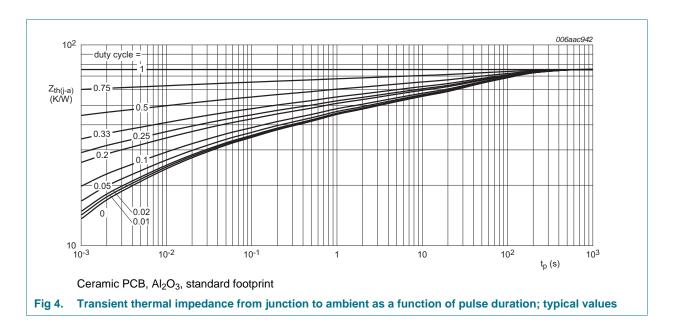


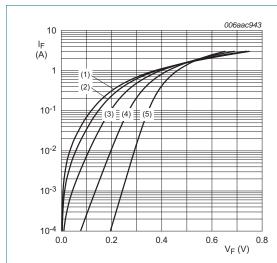
Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I_F = 100 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	270	300	mV
		I_F = 500 mA; pulsed; $t_p \le$ 300 µs; $\delta \le$ 0.02; T_j = 25 °C	-	360	410	mV
I _R	reverse current	V _R = 10 V; T _j = 25 °C	-	30	130	μA
		$V_R = 20 \text{ V}; T_j = 25 \text{ °C}$	-	70	300	μA
C _d	diode capacitance	$V_R = 1 \text{ V; } f = 1 \text{ MHz; } T_j = 25 ^{\circ}\text{C}$	-	35	-	pF
		$V_R = 10 \text{ V}; f = 1 \text{ MHz}; T_j = 25 \text{ °C}$	-	13	-	pF



(1)
$$T_i = 150 \, ^{\circ}C$$

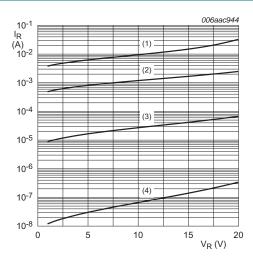
(2)
$$T_i = 125 \, ^{\circ}C$$

(3)
$$T_j = 85 \, ^{\circ}C$$

(4)
$$T_j = 25$$
 °C

(5)
$$T_j = -40 \, ^{\circ}\text{C}$$

Fig 5. Forward current as a function of forward voltage; typical values



(1)
$$T_i = 125 \, ^{\circ}C$$

(2)
$$T_i = 85 \, ^{\circ}C$$

(3)
$$T_j = 25 \, {}^{\circ}\text{C}$$

(4)
$$T_j = -40 \, ^{\circ}C$$

Fig 6. Reverse current as a function of reverse voltage; typical values

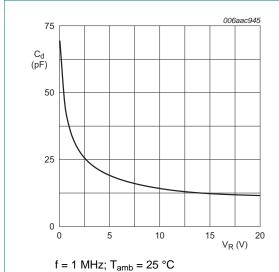
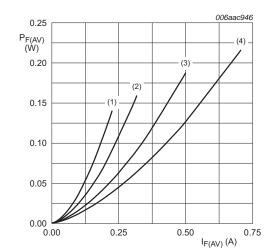


Fig 7. Diode capacitance as a function of reverse voltage; typical values



T_i = 150 °C

(1) $\delta = 0.1$

(2) $\delta = 0.2$

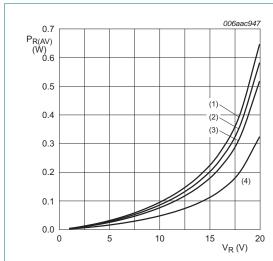
(3) $\delta = 0.5$

(4) $\delta = 1$

Fig 8. Average forward power dissipation as a function of average forward current; typical values

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T_i = 125 °C

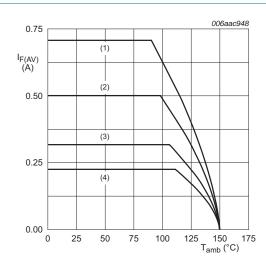
(1) $\delta = 1$

(2) $\delta = 0.9$

(3) $\delta = 0.8$

 $(4) \delta = 0.5$

Fig 9. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

 $T_i = 150 \, ^{\circ}C$

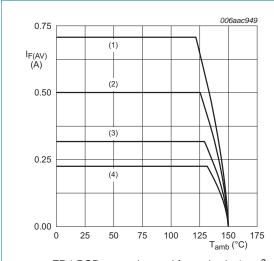
(1) $\delta = 1$ (DC)

(2) $\delta = 0.5$; f = 20 kHz

(3) $\delta = 0.2$; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig 10. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm²

T_i = 150 °C

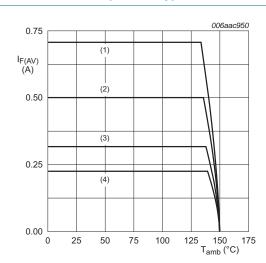
(1) $\delta = 1$ (DC)

(2) $\delta = 0.5$; f = 20 kHz

(3) $\delta = 0.2$; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig 11. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al₂O₃, standard footprint

T_i = 150 °C

(1) $\delta = 1$ (DC)

(2) $\delta = 0.5$; f = 20 kHz

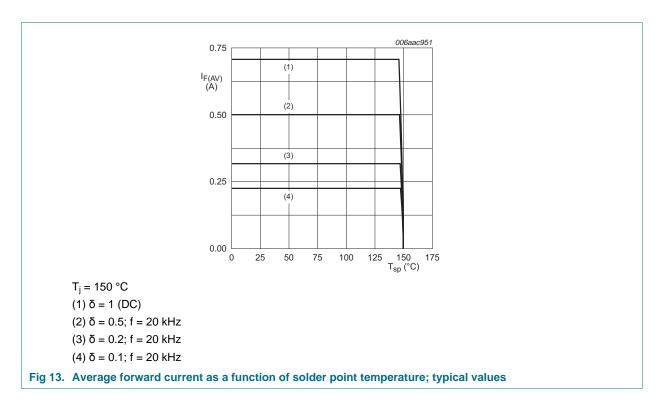
(3) $\delta = 0.2$; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

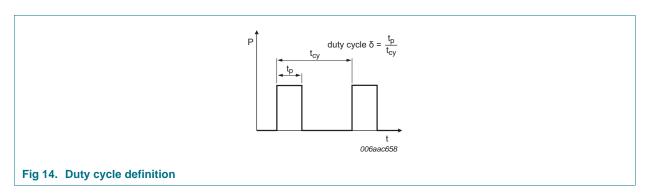
Fig 12. Average forward current as a function of ambient temperature; typical values

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8. Test information



The current ratings for the typical waveforms as shown in figures $\underline{10}$, $\underline{11}$, $\underline{12}$ and $\underline{13}$ are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

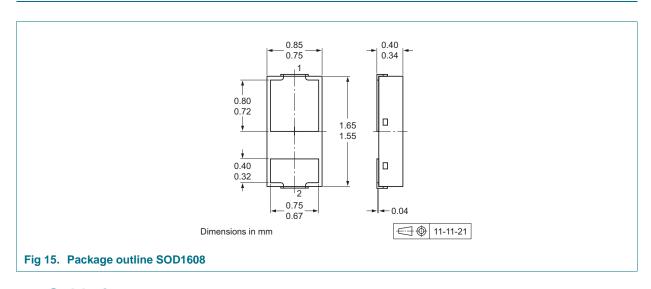
8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

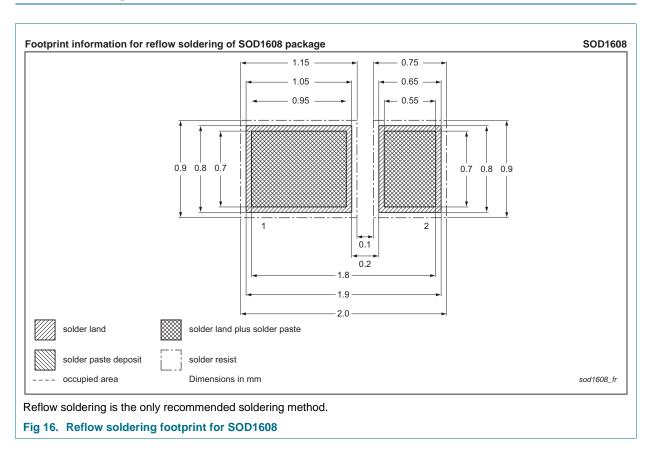
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9. Package outline



10. Soldering



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11. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG2005EPK v.1	20120112	Product data sheet	-	-

Downloaded from Elcodis.com electronic components distributor

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PMEG2005EPK

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14. Contents

1	Product profile
1.1	General description
1.2	Features and benefits1
1.3	Applications
1.4	Quick reference data1
2	Pinning information2
3	Ordering information
4	Marking
4.1	Binary marking code description
5	Limiting values3
6	Thermal characteristics3
7	Characteristics5
8	Test information
8.1	Quality information
9	Package outline
10	Soldering
11	Revision history10
12	Legal information11
12.1	Data sheet status
12.2	Definitions11
12.3	Disclaimers
12.4	Trademarks12
13	Contact information12

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